Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.215 inches
Overall Width:
0.293 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 repetitive peak reverse voltage
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Special Features:
Plated axial leads; mounting style, through-hole; epitaxial rectifier; current, 3 amps
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0